



Datasheet

HSA-X-S-1G4-SI

**Ultra High-Speed Photoreceiver
with Si-PIN Photodiode**



The picture shows the HSA-X-S-1G4-SI-FS with free space input. The photoreceiver will be delivered without post holder and post.

Features	<ul style="list-style-type: none"> • Bandwidth 10 kHz ... 1.4 GHz • Si-PIN detector • Spectral range 320 ... 1000 nm • Amplifier transimpedance (gain) 5×10^3 V/A • Conversion gain 2.55×10^3 V/W @ 760 nm 																															
Applications	<ul style="list-style-type: none"> • Spectroscopy • Ultra-fast pulse and transient measurements • Optical triggering • Optical front-end for oscilloscopes and ultra-fast A/D converters 																															
Specifications	<table border="0"> <tr> <td>Test conditions</td> <td colspan="2">$V_s = +15$ V, $T_A = 25$ °C, system impedance = 50 Ω</td> </tr> <tr> <td rowspan="2">Gain</td> <td>Amplifier transimpedance</td> <td>5×10^3 V/A (@ 50 Ω load)</td> </tr> <tr> <td>Conversion gain</td> <td>2.55×10^3 V/W (typ. @ 760 nm)</td> </tr> <tr> <td rowspan="3">Frequency Response</td> <td>Lower cut-off frequency (-3 dB)</td> <td>10 kHz</td> </tr> <tr> <td>Upper cut-off frequency (-3 dB)</td> <td>1.4 GHz (± 15 %)</td> </tr> <tr> <td>Rise/fall time (10 % - 90 %)</td> <td>250 ps (± 15 %)</td> </tr> <tr> <td rowspan="4">Input/Detector</td> <td>Detector material</td> <td>Si-PIN photodiode</td> </tr> <tr> <td rowspan="2">Active area</td> <td>FS-version: \varnothing 400 μm</td> </tr> <tr> <td>FC-version: integrated ball lens, suitable for fibers up to 400 μm core diameter</td> </tr> <tr> <td>Spectral range</td> <td>320 ... 1000 nm</td> </tr> <tr> <td rowspan="2">Max. optical peak input power</td> <td>370 μW AC</td> <td>(for linear amplification, @ 760 nm)</td> </tr> <tr> <td>10 mW CW</td> <td>(to prevent saturation, @ 760 nm)</td> </tr> <tr> <td>Noise</td> <td>Min. NEP</td> <td>32 pW/\sqrtHz (@ 760 nm, 100 MHz)</td> </tr> </table>	Test conditions	$V_s = +15$ V, $T_A = 25$ °C, system impedance = 50 Ω		Gain	Amplifier transimpedance	5×10^3 V/A (@ 50 Ω load)	Conversion gain	2.55×10^3 V/W (typ. @ 760 nm)	Frequency Response	Lower cut-off frequency (-3 dB)	10 kHz	Upper cut-off frequency (-3 dB)	1.4 GHz (± 15 %)	Rise/fall time (10 % - 90 %)	250 ps (± 15 %)	Input/Detector	Detector material	Si-PIN photodiode	Active area	FS-version: \varnothing 400 μ m	FC-version: integrated ball lens, suitable for fibers up to 400 μ m core diameter	Spectral range	320 ... 1000 nm	Max. optical peak input power	370 μ W AC	(for linear amplification, @ 760 nm)	10 mW CW	(to prevent saturation, @ 760 nm)	Noise	Min. NEP	32 pW/ \sqrt Hz (@ 760 nm, 100 MHz)
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Specifications (continued)

Output	Output impedance	50 Ω	(designed for 50 Ω load)
	Output VSWR	2.5 : 1	(@ f < 2.5 GHz)
	Output return loss	7.3 dB	(@ f < 2.5 GHz)
	Max. output voltage	1.9 V _{pp}	(@ 50 Ω load, for linear amplification)
	Output noise	typ. 3.6 mV _{RMS} or 24 mV _{pp} * (measurement BW: 4 GHz)	

* The peak-to-peak output noise is derived from the RMS noise as follows: $V_{pp} = V_{RMS} \times 6.6$
(99.9% of the time the output noise voltage will be within the specified peak-to-peak value.)

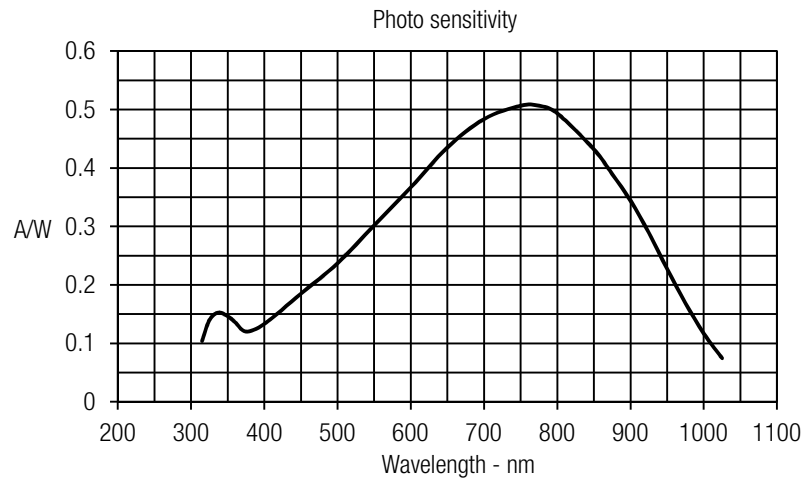
Power Supply	Supply voltage	+15 V, 130 mA typ. (depends on operating conditions, recommended power supply capability minimum 200 mA)
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Case	Weight	100 g (0.23 lbs)
	Material	AlMg4.5Mn, nickel-plated

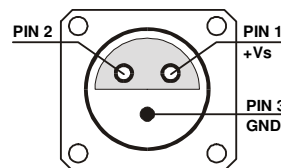
Temperature Range	Storage temperature	-40 ... +100 °C
	Operating temperature	0 ... +60 °C

Absolute Maximum Ratings	Power supply voltage	±20 V
	Optical input power	12 mW (averaged)

Spectral Response



Connectors	Input	HSA-X-S-1G4-SI-FS	25 mm round flange for free space applications
		HSA-X-S-1G4-SI-FC	FC fiber optic receptacle
	Output	SMA jack (female)	
	Power supply	Lemo® series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52)	
		Pin 1:	+15V
		Pin 2:	NC
		Pin 3:	GND



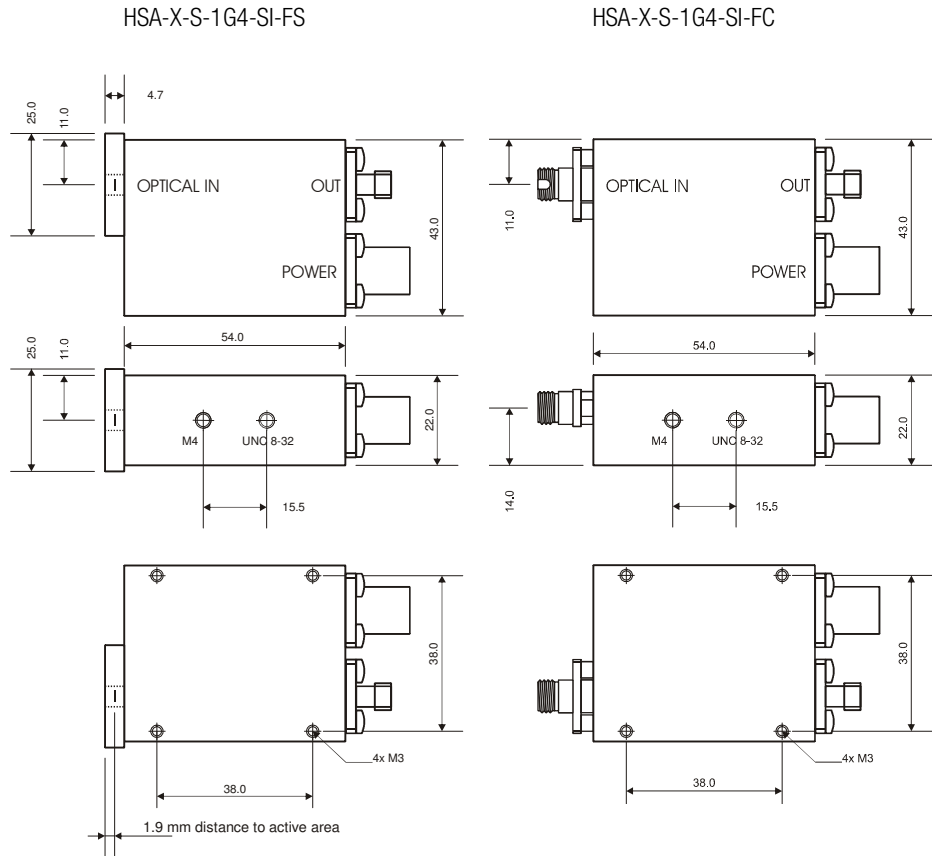
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Available Models

HSA-X-S-1G4-SI-FS
HSA-X-S-1G4-SI-FC
HSA-X-S

free space input
fiber optic receptacle
customized versions available on request

Dimensions



All Measures in mm unless otherwise noted.

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